1 k6r1004v1d_mx

- MDL Version: **01009**
- Title: **256K x 4 Asynchronous SRAM**
- Date: **29-May-2006**
- Memory Type: **sram**
- Vendor: **Samsung Electronics**

2 Timing Selection

This model can be configured to run in either timing-accurate or function-only (no timing) mode. In timing-accurate mode, the model implements both propagational delays and timing checks. In function-only mode, the model propagates output changes immediately and timing checks are disabled.

2.1 Function-only Mode Selection

To run in function-only mode, set the model's TimingVersion attribute to "none".

2.2 Timing-accurate Timing Version Selection

To run in timing-accurate mode, the model's TimingVersion attribute is set to select the device specific timing associated with a vendor's component. The following table provides a mapping between vendor component names and the corresponding TimingVersion attribute values.

Component to TimingVersion Mapping	
Component Name	TimingVersion
K6R1004V1D-10	10
K6R1004V1D-8	8

Note: By default, this model uses TimingVersion "8".

3 Sources

The following sources were used as references for behavioral and timing characteristics in the development of this model.

1. Samsung Electronics “June 2002”

4 Usage Notes

4.1 Configuring The Model

For information about configuring DesignWare Memory Models for use in simulation, refer to the installed version of the *Simulator Configuration Guide for Synopsys Models*. Or, for the most up-to-date version of this manual, see the *Simulator Configuration Guide for Synopsys Models* on the Synopsys external Web.

4.2 Using DesignWare Memory Models

For general information about using DesignWare Memory Models, refer to the installed version of the *DesignWare Memory Model User’s Manual*. Or, for the most up-to-date version of this manual, see the *DesignWare Memory Model User’s Manual* on the Synopsys external Web.

4.3 Using DesignWare SRAM Models

The DesignWare Memory Model documentation set also contains additional usage information that applies to all SRAM DesignWare Memory Models. For more information refer to the installed version of the *SRAM DesignWare Memory Model Reference*. Or, for the most up-to-date version of this manual, see the *SRAM DesignWare Memory Model Reference* on the Synopsys external Web.

4.4 Model Usage Notes

None

4.5 Model Port Description

The following table describes the pin interface for this model.

Model Port Description		
Port Name	Direction	Description
a[17:0]	in	Address Bus
cs_n	in	Chip Enable
io[4:1]	inout	IO Data Bus
oe_n	in	Output Enable
we_n	in	Write Enable

4.6 Default Attribute Setting

The following table describes the default attribute settings for this model.

Default Attribute Setting	
Model Attribute	Default Value
DefaultData	1111
DelayRange	Max
MemoryFile	.
MessageLevel	15
ModelAlias	.
ModelConfig	32’h0
ModelId	-2
TimingVersion	8

4.7 Timing Data for TimingVersion 10

The following table provides a listing of the timing data values modeled when the model’s TimingVersion is set to "10".

Timing Data for TimingVersion 10					
Parameter	Min	Typ	Max	Unit	Description
tAA	10.0	10.0	10.0	ns	Address to Output Data Valid
tACS1	10.0	10.0	10.0	ns	Chip Enable Asserted to Output Data Valid When Chip Deselect Time (tDESEL) violated
tACS2	10.0	10.0	10.0	ns	Chip Enable Asserted to Output Data Valid When Chip Deselect Time (tDESEL) not violated
tAS	0.0	-	-	ns	Address Setup to Write Start
tAW	7.0	-	-	ns	Address Setup to Write End
tCW	7.0	-	-	ns	Chip Enable Asserted to Write End
tDH	0.0	-	-	ns	Data Hold from Write End (Chip Enable)
tDW	5.0	-	-	ns	Data Setup to Write End

Timing Data for TimingVersion 10					
tHA_WE	0.0	-	-	ns	Address Hold from Write End (Write Enable)
tHD_WE	0.0	-	-	ns	Data Hold from Write End (Write Enable)
tHZ	0.0	5.0	5.0	ns	Chip Enable Deasserted to Output Data High Z
tLZ	3.0	-	-	ns	Chip Enable Asserted to Output Data Low Z
tOE	5.0	5.0	5.0	ns	Output Enable Asserted to Output Data Valid
tOH	3.0	-	-	ns	Output Data Invalid from Address Change
tOHZ	0.0	5.0	5.0	ns	Output Enable Deasserted to Output Data High Z
tOLZ	0.0	-	-	ns	Output Enable Asserted to Output Data Low Z
tOW	3.0	-	-	ns	Write Enable Deasserted to Output Data Low Z
tRC	10.0	-	-	ns	Read Cycle Time
tWC	10.0	-	-	ns	Write cycle time
tWHZ	0.0	5.0	5.0	ns	Write Enable Asserted to Output Data High Z
tWP	7.0	-	-	ns	Write Enable Pulse Width (Output Enable is Deasserted)
tWP1	10.0	-	-	ns	Write Enable Pulse Width (Output Enable is Asserted)
tWR	0.0	-	-	ns	Address Hold from Write End (Chip Enable)

4.8 Timing Data for TimingVersion 8

The following table provides a listing of the timing data values modeled when the model's TimingVersion is set to "8".

Timing Data for TimingVersion 8					
Parameter	Min	Typ	Max	Unit	Description
tAA	8.0	8.0	8.0	ns	Address to Output Data Valid
tACS1	8.0	8.0	8.0	ns	Chip Enable Asserted to Output Data Valid When Chip Deselect Time (tDESEL) violated
tACS2	8.0	8.0	8.0	ns	Chip Enable Asserted to Output Data Valid When Chip Deselect Time (tDESEL) not violated
tAS	0.0	-	-	ns	Address Setup to Write Start
tAW	6.0	-	-	ns	Address Setup to Write End
tCW	6.0	-	-	ns	Chip Enable Asserted to Write End
tDH	0.0	-	-	ns	Data Hold from Write End (Chip Enable)
tDW	4.0	-	-	ns	Data Setup to Write End
tHA_WE	0.0	-	-	ns	Address Hold from Write End (Write Enable)
tHD_WE	0.0	-	-	ns	Data Hold from Write End (Write Enable)

Timing Data for TimingVersion 8					
tHZ	0.0	4.0	4.0	ns	Chip Enable Deasserted to Output Data High Z
tLZ	3.0	-	-	ns	Chip Enable Asserted to Output Data Low Z
tOE	4.0	4.0	4.0	ns	Output Enable Asserted to Output Data Valid
tOH	3.0	-	-	ns	Output Data Invalid from Address Change
tOHZ	0.0	4.0	4.0	ns	Output Enable Deasserted to Output Data High Z
tOLZ	0.0	-	-	ns	Output Enable Asserted to Output Data Low Z
tOW	3.0	-	-	ns	Write Enable Deasserted to Output Data Low Z
tRC	8.0	-	-	ns	Read Cycle Time
tWC	8.0	-	-	ns	Write cycle time
tWHZ	0.0	4.0	4.0	ns	Write Enable Asserted to Output Data High Z
tWP	6.0	-	-	ns	Write Enable Pulse Width (Output Enable is Deasserted)
tWP1	8.0	-	-	ns	Write Enable Pulse Width (Output Enable is Asserted)
tWR	0.0	-	-	ns	Address Hold from Write End (Chip Enable)

4.9 Verilog Instantiation Example

Following is an example of instantiating this model within Verilog for the VCS simulator. In this example, a subset of the model's simulation attributes (Verilog parameters) are shown set to their default value. For a complete list of supported simulation attributes, see the table in section 4.6.

```
k6r1004v1d_mx_bus example_inst
  (
    .a    ( a    ),
    .cs_n ( cs_n ),
    .io   ( io   ),
    .oe_n ( oe_n ),
    .we_n ( we_n )
  );
defparam example_inst.DelayRange    = "Max";
defparam example_inst.MemoryFile    = ".";
defparam example_inst.MessageLevel  = "15";
defparam example_inst.ModelAlias    = ".";
defparam example_inst.ModelId       = "-2";
defparam example_inst.TimingVersion = "8";
```

4.10 VHDL Instantiation Example

Following is an example of instantiating this model within VHDL for the Scirocco simulator. In this example, a subset of the model's simulation attributes (VHDL generics) are shown set to their default value. For a complete list of supported simulation attributes, see the table in section 4.6.

```
example_inst : k6r1004v1d_mx
    generic map (
        DelayRange    => "Max",
        MemoryFile    => ".",
        MessageLevel  => "15",
        ModelAlias    => ".",
        ModelId       => "-2",
        TimingVersion => "8"
    )
    port map (
        a    => a,
        cs_n => cs_n,
        io   => io,
        oe_n => oe_n,
        we_n => we_n
    );
```

5 k6r1004v1d_mx Model History

Synopsys publishes model history and bug fixes on the *IP Directory for the k6r1004v1d_mx* . The behavior of DesignWare Memory Models may also be affected by revisions made to supporting utilities. For information concerning potential utility changes, please refer to *DesignWare Memory Model Release Notes* .